

#### AEM30300 Evaluation Board User Guide

## **Description**

The AEM30300 evaluation board is a printed circuit board (PCB) featuring all the needed components to operate the AEM30300 integrated circuit (IC).

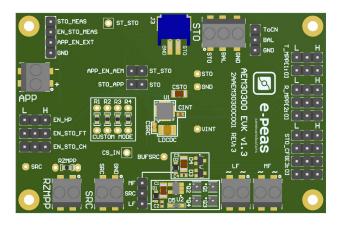
The AEM30300 evaluation board allows users to test the e-peas IC and analyze its performances in a laboratory-like setting.

It allows easy connections to the energy harvester and the storage element. It also provides all the configuration access to set the device in any one of the modes described in the datasheet. The control and status signals are available on standard pin headers, allowing users to wire for any usage scenario and evaluate the relevant performances.

The AEM30300 evaluation board is a plug and play, intuitive and efficient tool for making the appropriate decisions (component selection, operating modes, etc.) for the design of a highly efficient subsystem in your target application.

More detailed information about AEM30300 features can be found in the datasheet.

## **Appearance**



#### **Features**

Five two-way screw terminals

- Source of energy (DC).
- Source of energy (AC low frequency).
- Source of energy (AC medium frequency).
- ZMPP configuration.
- External output supply.

#### One three-way screw terminal

- Energy storage element (battery or (super)capacitor).

#### One 2-pin "Shrouded Header"

Alternative connector for the storage element.

#### 3-pin headers

- Maximum power point ratio (R MPP) configuration.
- Maximum power point timing (T\_MPP) configuration.
- Storage element voltage configuration.
- Dual-cell supercapacitor configuration.
- Modes configuration.

#### Provision for five resistors

- Custom mode configuration.
- ZMPP configuration.

#### Configuration by $0 \Omega$ resistors

- Cold start input configuration.

#### One 1-pin header

- Access to status pin.

### **Device Information**

Part Number	Dimensions	
2AAEM30300C001	76 mm x 50 mm	



## 1. Connections Diagram

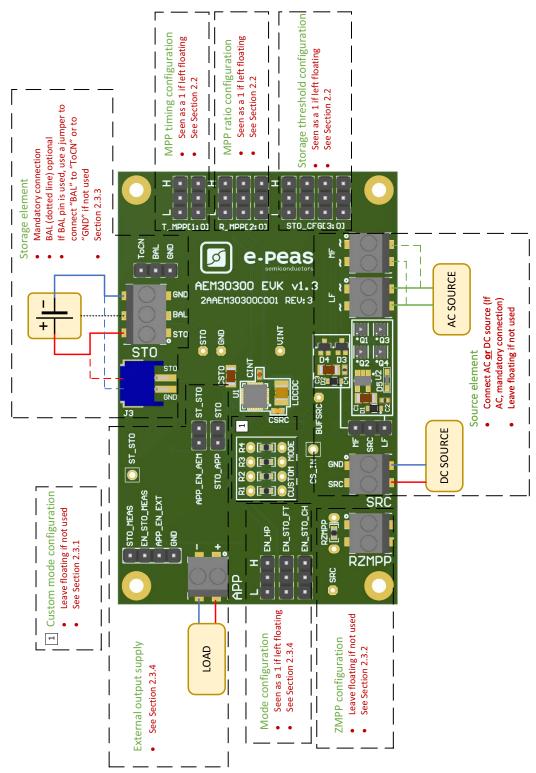


Figure 1: Connection Diagram



# 1.1. Signals Description

NAME	FUNCTION CONNECTION				
I	If used If not used				
Power signals					
SRC	Connection to the harvested energy source.	Connect the source element.			
STO	Connection to the energy storage element.	Connect the storage element in addition to CSTO (150 µF).	Do not remove CSTO.		
BAL	Connection to mid-point of the dual-cell supercapacitor.	Connect balancing and place a jumper shorting "BAL" and "ToCN".	Use a jumper to connect "BAL" to "GND".		
LF	Connection to the AC harvested energy source. (Low frequency).	Connect the source element.	Leave floating.		
MF	Connection to the AC harvested energy source. (Medium frequency).	Connect the source element.	Leave floating.		
АРР	Connection to the application.	Connect the jumper on APP_EN_AEM and a jumper on STO_APP.	Remove the jumper on APP_EN_AEM and the jumper on STO_APP.		
Debug signals					
VINT	Internal voltage supply.				
BUFSRC	Connection to an external capacitor buffering the buck-boost converter input.				
Configuration signals	3				
R_MPP[2:0]	Configuration of the MPP ratio.	Connect jumpers.	Leave floating.		
T_MPP[1:0]	Configuration of the MPP timing. Connect jum		Leave floating.		
STO_CFG[3:0]	Configuration of the threshold voltages for the energy storage element.	Connect jumpers.	Leave floating.		
ZMPP Configuration of the constant impedance MPP.		Use resistor R <sub>ZMPP</sub> .	Leave floating.		
Control signals					
EN_HP Enabling pin for the high-power mode.		Connect jumper.			
EN_STO_FT	_STO_FT Enabling pin for the feed-through feature.		Connect jumper.		
EN_STO_CH Enabling pin for the storage charging.		Connect jumper.			
APP_EN_AEM  APP_EN_EXT  Enabling pin for the application supply.		Connect jumper.			
		External signal.	Leave floating.		
EN_STO_MEAS	Enabling pin for the storage element measure.	External signal.	Leave floating.		
Status signals					
ST_STO	Logic output. Asserted when the storage device voltage rises above the V <sub>CHRDY</sub> threshold. Reset when the storage device voltage drops below V <sub>OVDIS</sub> threshold. High level is V <sub>STO</sub> .				
STO_MEAS Voltage level on the storage element.		High level in EN_STO_MEAS (from external signal) to enable the measure.	Leave floating EN_STO_MEAS.		

Table 1: Signals Description



## 2. General Considerations

## 2.1. Safety Information

Always connect the elements in the following order:

- 1. Reset the board: Short VINT, STO and SRC test points to GND.
- 2. Completely configure the PCB (jumpers/resistors):
  - MPP configuration (Ratio/Timing).
  - Battery configuration.
  - Balancing circuit configuration.
  - Mode configuration.
- 3. Connect the storage elements on STO.
- 4. Connect the source (DC or AC) to the SRC connector.

To avoid damaging the board, users are required to follow this procedure.

The pin "BAL" cannot remain floating.

## 2.2. Basic Configurations

Configuration pins				Storage ele	ment thresho	old voltages	Typical use
STO_CFG[3]	STO_CFG[2]	STO_CFG[1]	STO_CFG[0]	V <sub>OVDIS</sub>	V <sub>CHRDY</sub>	V <sub>OVCH</sub>	
0	0	0	0	3.00 V	3.50 V	4.05 V	Li-ion battery
0	0	0	1	2.80 V	3.10 V	3.60 V	LiFePO4 battery
0	0	1	0	1.85 V	2.40 V	2.70 V	Dual-cell NiMH battery
0	0	1	1	0.20 V	1.00 V	4.65 V	Dual-cell supercapacitor
0	1	0	0	0.20 V	1.00 V	2.60 V	Single-cell supercapacitor
0	1	0	1	1.00 V	1.20 V	2.95 V	Single-cell supercapacitor
0	1	1	0	1.85 V	2.30 V	2.60 V	NGK
0	1	1	1	Custom Mode (single-cell NiMH, LiC, etc.)			
1	0	0	0	1.10 V	1.25 V	1.50 V	Ni-Cd 1 cells
1	0	0	1	2.20 V	2.50 V	3.00 V	Ni-Cd 2 cells
1	0	1	0	1.45 V	2.00 V	4.65 V	Dual-cell supercapacitor
1	0	1	1	1.00 V	1.20 V	2.60 V	Single-cell supercapacitor
1	1	0	0	2.00 V	2.30 V	2.60 V	Micro batteries
1	1	0	1	3.00 V	3.50 V	4.35 V	Li-Po battery
1	1	1	0	2.60 V	2.70 V	4.00 V	Tadiran TLI1020A
1	1	1	1	2.60 V	3.50 V	3.90 V	Tadiran HLC1020

Table 2: Storage Element Configuration Pins



Со	nfiguration p	MPPT ratio	
R_MPP[2]	R_MPP[1]	R_MPP[0]	V <sub>MPP</sub> / V <sub>OC</sub>
0	0	0	35%
0	0	1	50%
0	1	0	60%
0	1	1	65%
1	0	0	70%
1	0	1	75%
1	1	0	80%
1	1	1	ZMPP

Table 3: MPP Ratio Configuration Pins

Configur	ation pins	MPPT timing		
T_MPP[1]	T_MPP[0]	Sampling duration	Sampling period	
0	0	3.83 ms	18.28 ms	
0	1	5.1 ms	280 ms	
1	1 0 1 1		1.12 s	
1			71.7 s	

Table 4: MPP Timing Configuration Pins



## 2.3. Advanced Configurations

A complete description of the system constraints and configurations is available in the AEM30300 datasheet "System Configuration" Section.

A reminder on how to calculate the configuration resistors value is provided below. Calculation can be made with the help of the spreadsheet found on the e-peas website.

#### 2.3.1. Custom Mode

In addition to the pre-defined protection levels, the custom mode allows users to define their own levels via resistors R1 to R4, according to the following equations:

- $R_T = R_1 + R_2 + R_3 + R_4$
- $1M\Omega \le R_T \le 100M\Omega$
- $R_1 = R_T \cdot \frac{1V}{V_{OVCH}}$
- $R_2 = R_T \cdot \left(\frac{1V}{V_{CHRDY}} \frac{1V}{V_{OVCH}}\right)$
- $R_3 = R_T \cdot \left(\frac{1V}{V_{OVDIS}} \frac{1V}{V_{CHRDY}}\right)$
- $R_4 = R_T \cdot \left(1 \frac{1V}{V_{OVDIS}}\right)$

User must ensure that the protection levels satisfy the following conditions:

- $V_{CHRDY} + 0.05V \le V_{OVCH} \le 4.5V$
- $V_{OVDIS} + 0.05V \le V_{CHRDY} \le V_{OVCH} 0.05V$
- $1V \le V_{OVDIS}$

If unused, leave the resistor footprints (R1 to R4) empty.

#### 2.3.2. ZMPP Configuration

If this configuration is chosen (see Table 3), the AEM30300 regulates  $V_{SRC}$  at a voltage equals to the product of  $R_{ZMPP}$  times the current available at the source SRC.

-  $10 \Omega \le R_{7MPP} \le 1 M\Omega$ 

If unused, leave the resistor footprint R<sub>ZMPP</sub> empty.

#### 2.3.3. Balancing Circuit Configuration

When using a dual-cell supercapacitor (that does not already include a balancing circuit), enable the balancing circuit configuration to ensure equal voltage on both cells. To do so:

- Connect the node between the two supercapacitor cells to BAL (on STO connector).

- Use a jumper to connect "BAL" to "ToCN".

If unused, use a jumper to connect "BAL" to "GND".

#### 2.3.4. Mode Configuration

EN HP

When EN\_HP is pulled up to VINT, the DCDC converter is set to HIGH POWER MODE. This allows higher currents to be extracted from the buck-boost input (SRC) to the buck-boost output (STO or VINT).

- Use a jumper to connect EN\_HP to 1 to enable the high-power mode.
- Use a jumper to connect EN\_HP to 0 to disable the high-power mode.

EN\_STO\_CH

To disable battery charging, the 3-pin header is available.

- Use a jumper to connect the EN\_STO\_CH to 1 to enable the charge of the storage element.
- Use a jumper to connect the EN\_STO\_CH to 0 to disable the charge of the storage element.

An internal pull-up resistor is setting the  $EN\_STO\_CH$  at 1 by default.

EN STO FT

To disable the source to storage element feed-through, the 3-pin header is available.

- Use a jumper to connect the EN\_STO\_FT to 1 to activate the feature.
- Use a jumper to connect the EN\_STO\_FT to 0 to disable the feature.

#### 2.3.5. Rectifier Use

When a rectifier is used, it is recommended to use the ZMPP configuration. With a MPP ratio, the voltage level of the MPPT will not be the right one. In fact, due to the rectifier capacitor, the open-circuit evaluation will not be done correctly.

#### 2.3.6. External Output Supply

The AEM30300 is a battery charger. An external application can be supplied from the battery using the APP connector in the EVK.

To enable this feature a jumper may be placed connecting STO to STO\_APP. A switch will connect the storage element to the APP connector if one of these two signals, APP\_EN\_AEM or APP\_EN\_EXT, have a high logic level.



Placing a jumper linking ST\_STO and APP\_EN\_AEM will enable the APP output when the voltage in the storage element rises above V<sub>CHRDY</sub> (if the AEM comes from RESET STATE) and while the storage element voltages is over V<sub>OVDIS</sub>. The AEM30300 goes to RESET STATE if there is no more energy to harvest in the SRC input, the ST\_STO signal is also reset. The APP\_EN\_EXT signal may be asserted from the application to continue using the APP output when the AEM is in RESET STATE.

The storage element voltage can be measured in the STO\_MEAS pin. This pin is connected to a power gated resistor bridge that can be enabled through the EN\_STO\_MEAS signal.



## 3. Functional Tests

This section presents a few simple tests that allow the user to understand the functional behavior of the AEM30300. To avoid damaging the board, follow the procedure found in Section 2.1 "Safety Information". If a test has to be restarted make sure to properly reset the system to obtain reproducible results.

The following functional tests were made using the following setup:

- $R_MPP[2:0] = 000.$
- T MPP[1:0] = 01.
- STO\_CFG[3:0] = 0000.
- EN\_HP = 1.
- EN STO FT = 0.
- EN\_STO\_CH = 1.
- Storage element: Capacitor (4.7 mF + CSTO).
- SRC: current source (1mA or 100uA) with voltage compliance (4V).

Setup can be adapted to match user's system as long as the input and cold-start constraints are met (see the AEM30300 datasheet "Introduction" Section).

## 3.1. Start-up

The following example allows the user to observe the behavior of the AEM30300 in Wake-up state.

#### Setup

- Place the probes on the nodes to be observed.
- Referring to Figure 1, follow steps 1 to 5 explained in Section 2.1 "Safety Information".

#### **Observations and Measurements**

- STO: Voltage rises as the power provided by the source is transferred to the storage element.
- ST\_STO: Asserted when the voltage on STO rises above V<sub>CHRDY</sub>.

#### 3.2. Shutdown

This test allows users to observe the behavior of the AEM30300 when the system is running out of energy.

#### Setup

- Place the probes on the nodes to be observed.
- Referring to Figure 1, follow steps 1 to 5 explained in Section 2.1 "Safety Information". Configure the board in the desired state and start the system (see Section 3.1).
- Let the system reach a steady state (i.e. voltage on STO between V<sub>CHRDY</sub> and V<sub>OVCH</sub> and ST\_STO asserted.
- Remove your source element and let the system discharge through quiescent current.

#### **Observations and Measurements**

- STO: Voltage decreases as the system consumes the power accumulated in the storage element. The voltage reaches V<sub>OVDIS</sub>.
- ST\_STO: De-asserted when the storage element is running out of energy (V<sub>OVDIS</sub>).

#### 3.3. Cold Start

The following test allows the user to observe the minimum voltage required to coldstart the AEM30300. To prevent leakage current induced by the probe the user should avoid probing any unnecessary node. Make sure to properly reset the board to observe the cold-start behavior.

#### Setup

- Place the probes on the nodes to be observed.
- Referring Figure 1, follow steps 1 and 2 explained in Section 2.1. Configure the board in the desired state.
   Do not plug any storage element in addition to CSTO.
- SRC: Connect your source element.

#### **Observations and Measurements**

- SRC: Equal to the cold-start voltage during the coldstart phase. Regulated at the selected MPPT percentage of V<sub>OC</sub> when cold start is over. Be careful that the cold-start phase time will shorten with the input power. Limit it to ease the observation.
- STO: Starts to charge the storage element when the cold-start phase is over.

# **3.4. Dual-cell Supercapacitor Balancing Circuit**

This test allows users to observe the balancing circuit behavior that maintains the voltage on BAL at half the voltage on STO.



#### Setup

- Following steps 1 and 2 explained in Section 2.1 and referring to Figure 1, configure the board in the desired state. Plug the jumper linking "BAL" to "ToCN".
- STO: Connect capacitor C1 between the positive (+) and the BAL pins and a capacitor C2 between BAL and the negative (-) pins. Select C1 and C2 so that:
  - C1 ≠ C2
  - C1 > 1mF
  - C2 > 1mF
  - $\frac{\text{C2} \cdot \text{V}_{\text{CHRDY}}}{\text{C1}} \ge 0.9 \text{V}$
- SRC: Plug your source element to start the power flow to the system.

#### **Observations and Measurements**

- BAL: Equals to half the voltage on STO.

Do not leave BAL floating, doing so could damage the AEM.

## 3.5. Source to Storage Element Feed-Through

This example allows users to observe the feed-through feature.

#### Setup

- Place the probes on the nodes to be observed.
- Referring to Figure 1, follow steps 1 to 5 explained in Section 2.1 "Safety Information". Configure the board in the desired state and start the system (see Section 3.1).
- Let the system reach a steady state (i.e. voltage on STO between V<sub>CHRDY</sub> and V<sub>OVCH</sub> and ST\_STO asserted.
- EN\_STO\_FT: Connect to VINT.
- SRC: current source (1mA or 100uA) with voltage compliance (5V).
- Connect a capacitor (>1mF) on SRC and STO to avoid perturbation due to the SMU behavior.

#### **Observations and Measurements**

- STO: The current from the source is transfered directly to the storage element.



# 4. Schematics

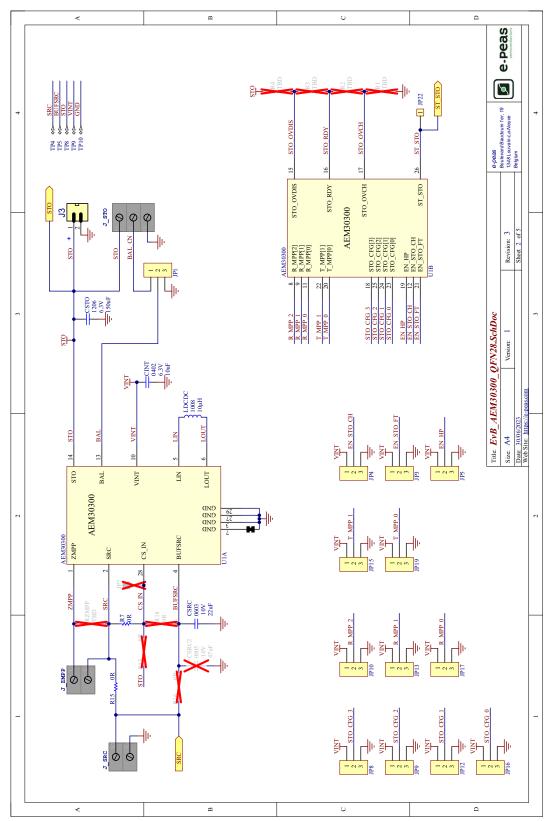


Figure 2: Schematic Part 1



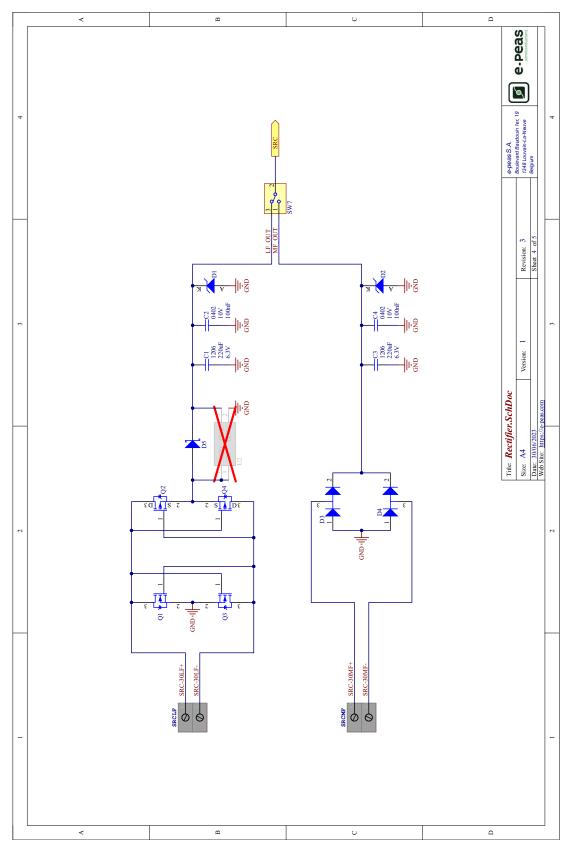


Figure 3: Schematic Part 2



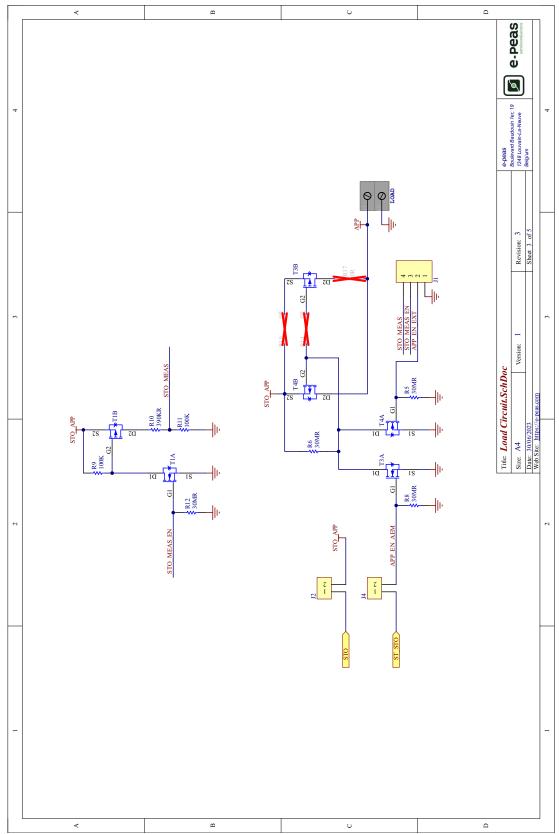


Figure 4: Schematic part 3



# 5. Revision History

Revision	Date	Description
1.0	September, 2021	Creation of the document.
1.1	November, 2022	Fixed some inconsistencies and updated images.
1.2 August, 2023 Images and		Images and schematics update to EvK v1.3.

Table 5: Revision History